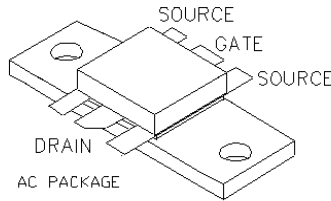




General Description

Silicon VDMOS and LDMOS transistors designed specifically for broadband RF applications. Suitable for Military Radios, Cellular and Paging Amplifier Base Stations, Broadcast FM/AM, MRI, Laser Driver and others.

"Polyfet"™ process features gold metal for greatly extended lifetime. Low output capacitance and high F_t enhance broadband performance



PATENTED GOLD METALIZED SILICON GATE ENHANCEMENT MODE RF POWER VDMOS TRANSISTOR

7.5 Watts Single Ended

Package Style AC

HIGH EFFICIENCY, LINEAR, HIGH GAIN, LOW NOISE

ABSOLUTE MAXIMUM RATINGS (TC = 25 °C)

Total Device Dissipation	Junction to Case Thermal Resistance	Maximum Junction Temperature	Storage Temperature	DC Drain Current	Drain to Gate Voltage	Drain to Source Voltage	Gate to Source Voltage
40 Watts	5 °C/W	200 °C	-65 °C to 150 °C	2.4 A	70 V	70V	30V

RF CHARACTERISTICS (7.5WATTS OUTPUT)

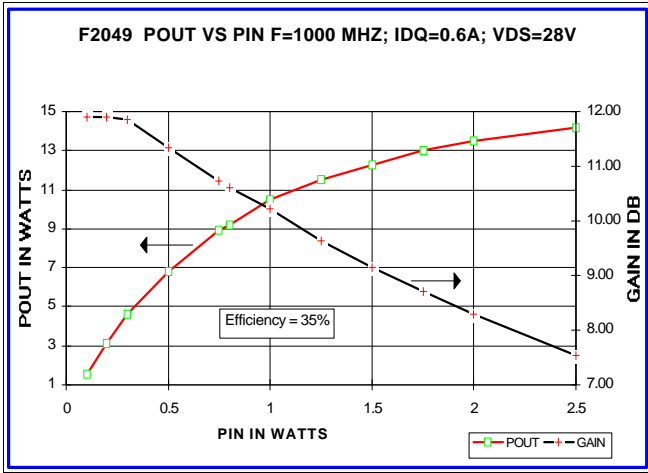
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Gps	Common Source Power Gain	10			dB	$I_{dq} = 0.6 A, V_{ds} = 28.0V, F = 1000 MHz$
η	Drain Efficiency		45		%	$I_{dq} = 0.6 A, V_{ds} = 28.0V, F = 1000 MHz$
VSWR	Load Mismatch Tolerance			20:1	Relative	$I_{dq} = 0.6 A, V_{ds} = 28.0V, F = 1000 MHz$

ELECTRICAL CHARACTERISTICS (EACH SIDE)

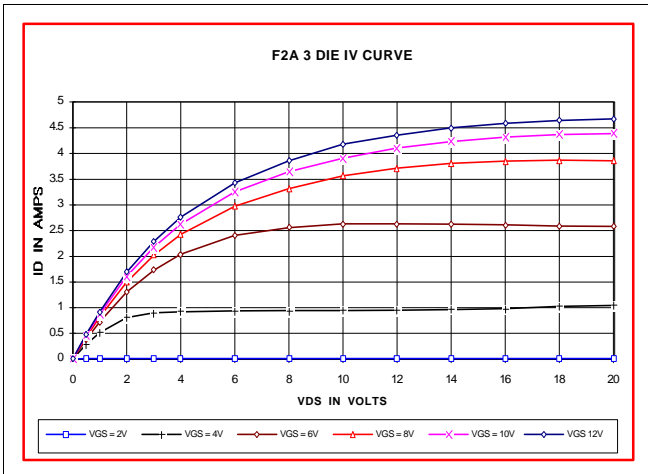
SYMBOL	PARAMETER	MIN	TYP	MAX	UNITS	TEST CONDITIONS
Bvdss	Drain Breakdown Voltage	65			V	$I_{ds} = 0.03 A, V_{gs} = 0V$
Idss	Zero Bias Drain Current			0.6	mA	$V_{ds} = 28.0 V, V_{gs} = 0V$
Igss	Gate Leakage Current			1	uA	$V_{ds} = 0 V, V_{gs} = 30V$
Vgs	Gate Bias for Drain Current	1		7	V	$I_{ds} = 0.06 A, V_{gs} = V_{ds}$
gM	Forward Transconductance		0.6		Mho	$V_{ds} = 10V, V_{gs} = 5V$
Rdson	Saturation Resistance		1.4		Ohm	$V_{gs} = 20V, I_{ds} = 3A$
Idsat	Saturation Current		3.6		Amp	$V_{gs} = 20V, V_{ds} = 10V$
Ciss	Common Source Input Capacitance		27		pF	$V_{ds} = 28.0 V, V_{gs} = 0V, F = 1 MHz$
Crss	Common Source Feedback Capacitance		3		pF	$V_{ds} = 28.0 V, V_{gs} = 0V, F = 1 MHz$
Coss	Common Source Output Capacitance		18		pF	$V_{ds} = 28.0 V, V_{gs} = 0V, F = 1 MHz$

F2049

POUT VS PIN GRAPH



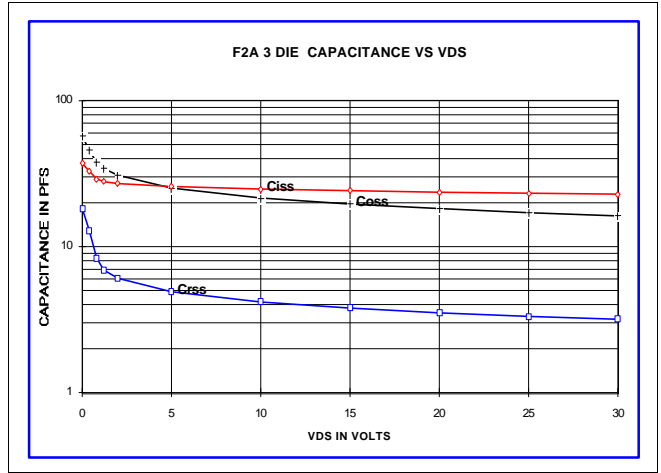
IV CURVE



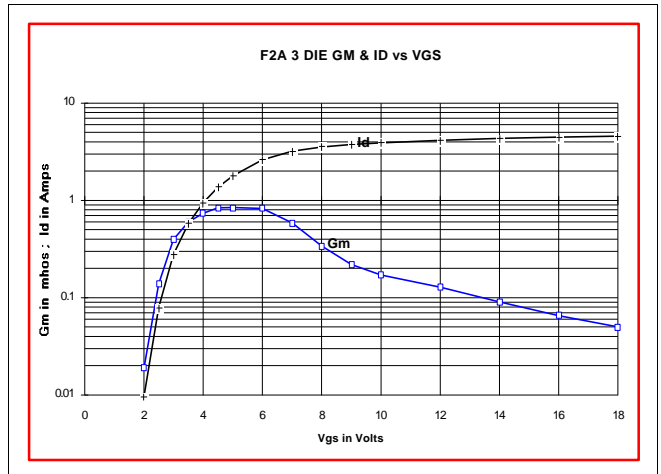
S11 AND S22 SMITH CHART

PLEASE CALL OFFICE FOR UPDATE

CAPACITANCE VS VOLTAGE



ID AND GM VS VGS



PACKAGE DIMENSIONS IN INCHES

